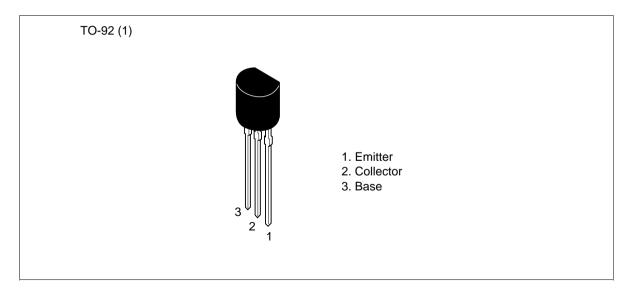
Silicon NPN Triple Diffused

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Application

- High voltage amplifier
- TV Video output

Outline



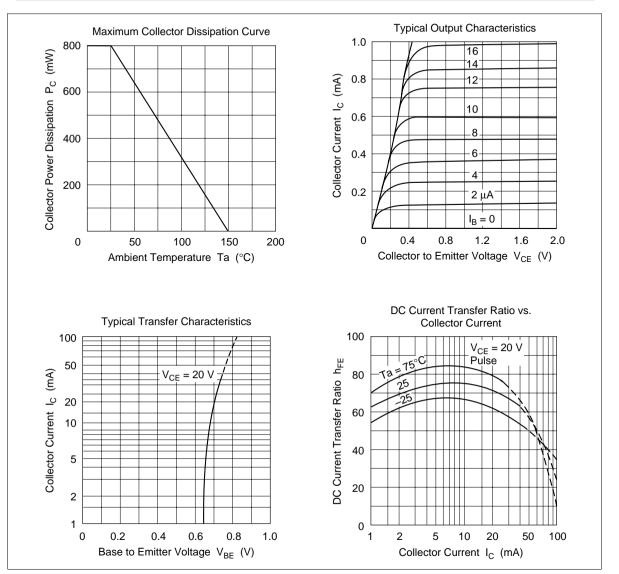


Absolute Maximum Ratings ($Ta = 25^{\circ}C$)

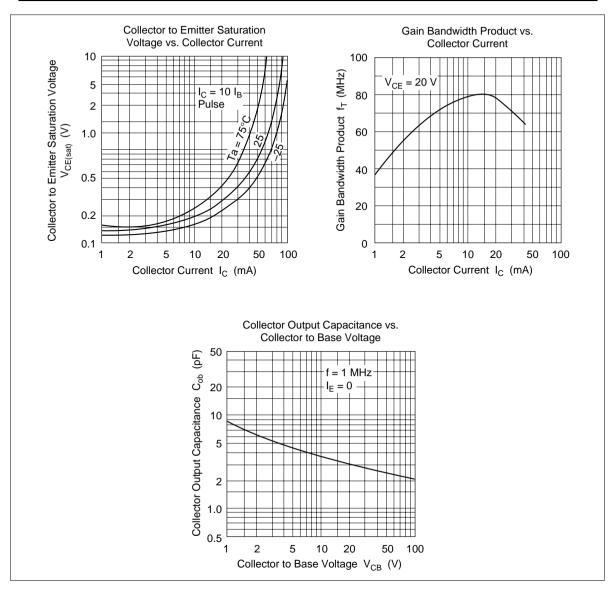
Item	Symbol	Ratings	Unit
Collector to base voltage	V _{CBO}	300	V
Collector to emitter voltage	V _{CEO}	300	V
Emitter to base voltage	V _{EBO}	5	V
Collector current	Ι _c	100	mA
Collector power dissipation	Pc	800	mW
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

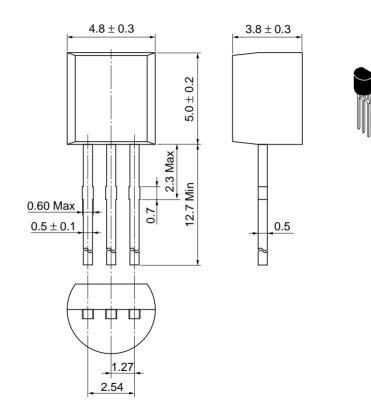
Electrical Characteristics ($Ta = 25^{\circ}C$)

Item	Symbol	Min	Тур	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{\rm (BR)CBO}$	300	_	_	V	$I_{c} = 10 \ \mu A, \ I_{E} = 0$
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	300	—	_	V	$I_c = 1 \text{ mA}, R_{BE} = \infty$
Emitter to base breakdown voltage	$V_{(BR)EBO}$	5	—	_	V	$I_{\rm E} = 10 \ \mu A, \ I_{\rm C} = 0$
Collector cutoff current	I _{CEO}	—	—	1.0	μΑ	V_{ce} = 250 V, R_{Be} = ∞
DC current transfer ratio	h_{FE}	30		200		$V_{ce} = 20 \text{ V}, I_c = 20 \text{ mA}$
Collector to emitter saturation voltage	$V_{\text{CE(sat)}}$	—	_	1.5	V	$I_{c} = 20 \text{ mA}, I_{B} = 2 \text{ mA}$
Gain bandwidth product	f _T	50	80		MHz	$V_{ce} = 20 \text{ V}, \text{ I}_{c} = 20 \text{ mA}$
Collector output capacitance	Cob	—	_	4.0	pF	$V_{_{CB}} = 20 \text{ V}, \text{ I}_{_{E}} = 0, \text{ f} = 1 \text{ MHz}$



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Hitachi Code	TO-92 (1)
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	0.25 g

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